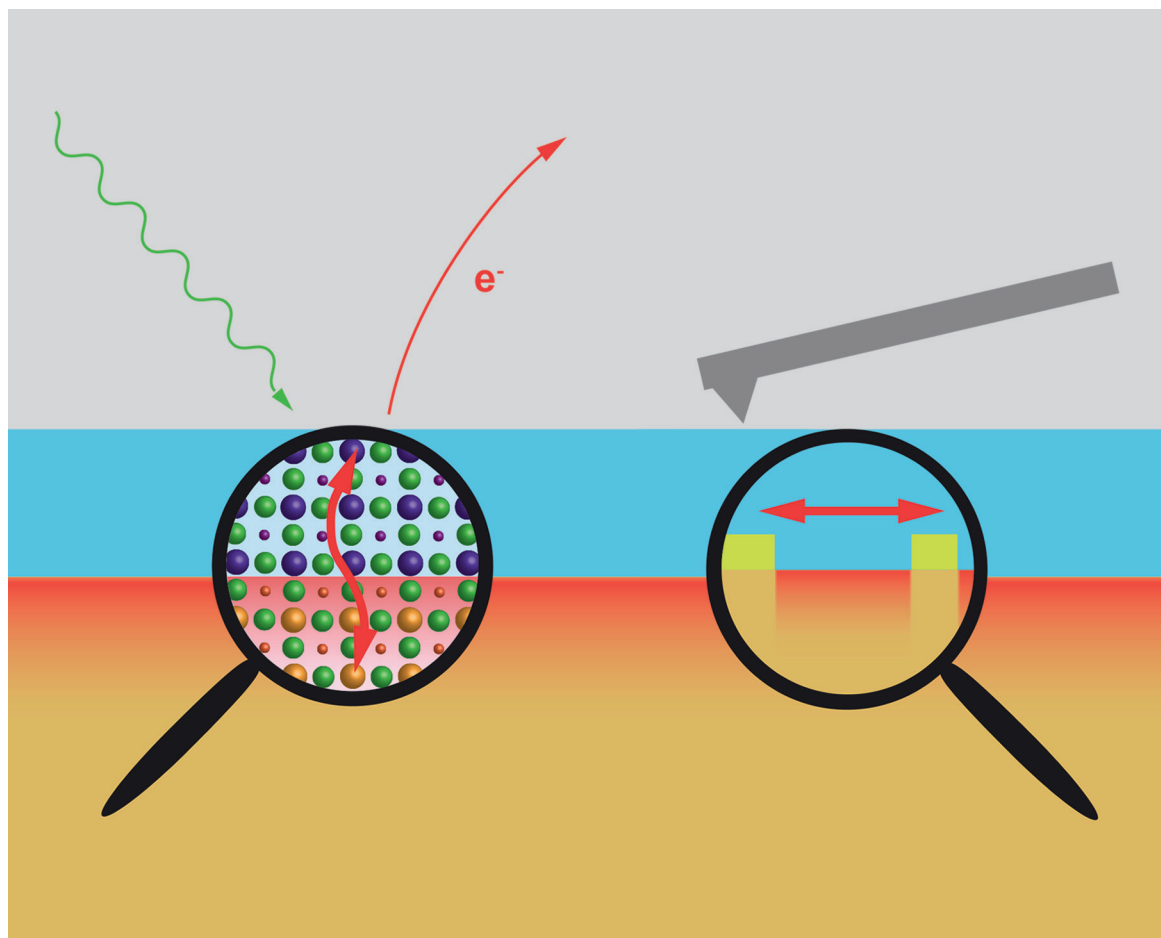




Controlling the electrical properties of oxide heterointerfaces through their interface chemistry

Marc-André Rose

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